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# **RF2376** CELLULAR TDMA/CDMA LINEAR VARIABLE GAIN AMPLIFIER

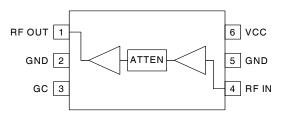
Package: SOT23-6

### **Features**

- 50dB Linear Gain Control Range
- 27 dB Maximum Gain
- Single 2.7V to 3.3V Supply
- 30mA Supply Current
- High Linearity
- 7 dB Noise Figure

### **Applications**

- CDMA Cellular Handsets
- TDMA Cellular Handsets



Functional Block Diagram

### **Product Description**

Preliminary

The RF2376 is a linear variable gain amplifier suitable for use in TDMA and CDMA systems in the cellular band. The features of this device include linear gain control, high gain, and low noise figure. The IC is manufactured on an advanced Gallium Arsenide Heterojunction Bipolar Transistor (GaAs HBT) process and is featured in an industry-standard miniature 6-lead plastic SOT package.

#### **Ordering Information**

RF2376 PCBA

Fully Assembled Evaluation Board

### Optimum Technology Matching® Applied

🗹 GaAs HBT	SiGe BiCMOS	GaAs pHEMT	🗌 GaN HEMT
GaAs MESFET	🗌 Si BiCMOS	Si CMOS	
🗌 InGaP HBT	SiGe HBT	🗌 Si BJT	

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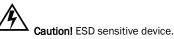
## Preliminary



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#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Supply Voltage	0 to +5.0	V <sub>DC</sub>
DC Current	100	mA
Operating Ambient Temperature	-20 to +85	°C
Storage Temperature	-40 to +150	°C



Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EUDirective2002/95/EC (at time of this document revision).

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Parameter	Specification		Unit	Condition		
Parameter	Min.	Тур.	Max.	Unit	Condition	
Overall					V <sub>CC</sub> =2.8V, V <sub>GC</sub> =2.0V, T=25 °C	
Operating Frequency		836		MHz		
Usable Frequency Range		800 to >1000		MHz		
Maximum Small Signal Gain	24	27	30	dB		
Linear Gain Control Range	50			dB		
Gain Control Slope		70		dB/V	Maximum gain.	
Input VSWR		1.5:1	2.5:1		Over entire gain control range	
Output IP3	+22	+25		dBm		
Noise Figure		7		dB	Maximum gain	
Maximum Average Output Power		+8		dBm	TDMA modulation	
Adjacent Channel Power Rejection		-33	-32	dBc	TDMA modulation; P <sub>OUT</sub> =+8dBm	
Alternate Channel Power Rejection		-61	-57	dBc	TDMA modulation; P <sub>OUT</sub> =+8dBm	
Maximum Average Output Power		+10		dBm	CDMA modulation; V <sub>CC</sub> =3.0V, maximum gain setting, ACPR <u>&lt;</u> -52dBc.	
Adjacent Channel Power Rejection		-53		dBc	CDMA modulation; $V_{CC}$ =3.0V. For P <sub>IN</sub> >-23dBm, adjustment of P <sub>IN</sub> is required to maintain ACPR performance over gain control range. For P <sub>IN</sub> $\leq$ -23dBm, ACPR performance is maintained over entire gain control range.	
Alternate Channel Power Rejection		-67		dBc	CDMA modulation; P <sub>OUT</sub> =+10dBm, V <sub>CC</sub> =3.0V.	
Power Supply					T=25°C	
Supply Voltage		2.8		V	Specifications	
		2.7 to 3.3		V	Operating range	
Gain Control Voltage		0 to 2.0		V		
Supply Current	25	30	40	mA	V <sub>CC</sub> =2.8V, V <sub>GC</sub> =2.0V	
		34		mA	V <sub>CC</sub> =3.0V, V <sub>GC</sub> =2.0V	
			18	mA	V <sub>CC</sub> =2.8V, V <sub>GC</sub> =0.4V	
V <sub>GC</sub> Current			1.5	mA		



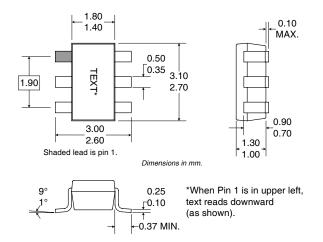




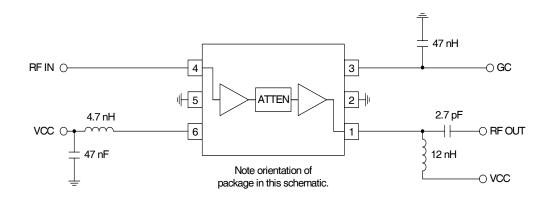
Pin	Function	Description	Interface Schematic
1	RF OUT	RF output pin. This pin is DC coupled and requires V <sub>CC</sub> through a bias inductor sized accordingly to provide a high pass transformation with a series capacitor.	
2	GND	Ground connection. Keep traces physically short and connect immediately to ground plane for best performance.	
3	GC	Analog gain control pin. This pin controls the gain of the IC. Minimum gain occurs at $V_{GC}$ <0.4V and maximum gain is achieved with $V_{GC}$ =2.0V. 50dB of linear gain control with little variation of input P <sub>1dB</sub> is available.	
4	RF IN	RF input pin. This pin is AC coupled.	
5	GND	Ground connection. Keep traces physically short and connect immediately to ground plane for best performance.	
6	VCC	Power supply. This pin should be connected to a regulated supply and requires a bypass capacitor. Voltage is supplied through this pin to the first stage collector; this voltage also controls the bias. Gain may be tuned by adjusting the value of the feed inductor.	





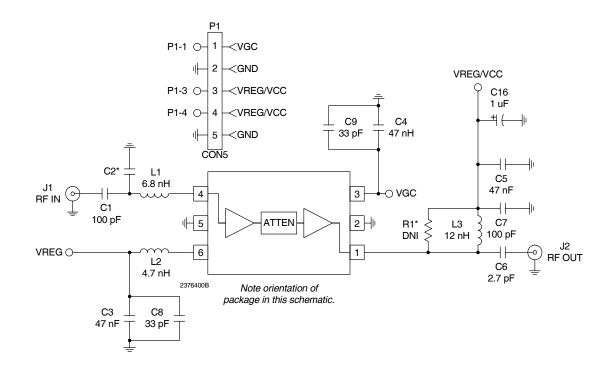


### **Application Schematic**





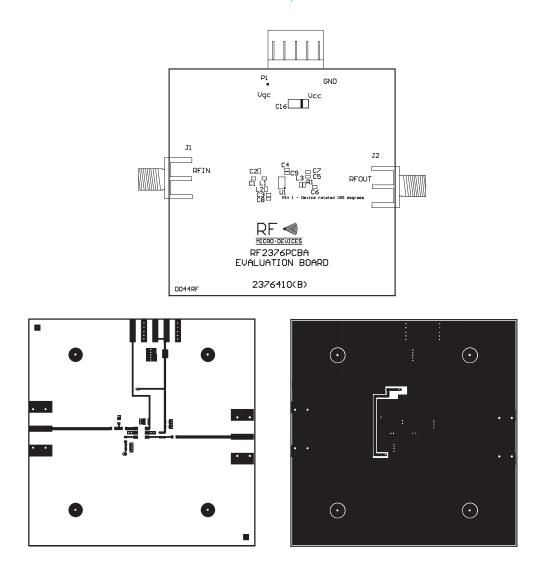
### **Evaluation Board Schematic**





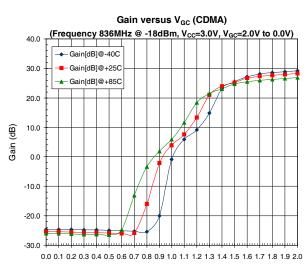


### **Evaluation Board Layout** Board Size 2.0" x 2.0" Board Thickness 0.028"; Board Material FR-4

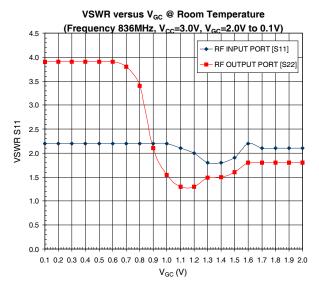




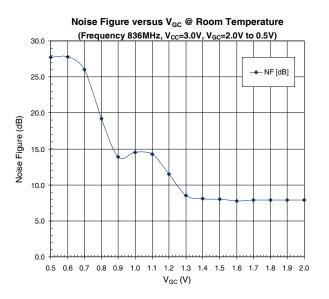
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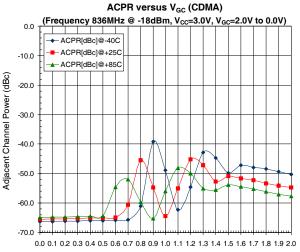




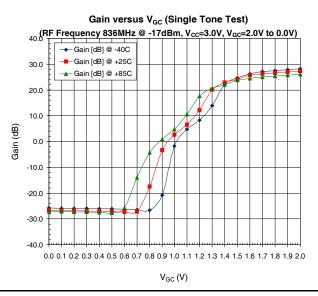


Alternate Channel Power versus V<sub>GC</sub> (CDMA) (Frequency 836MHz @ -18dBm, V<sub>CC</sub>=3.0V, V<sub>GC</sub>=2.0V to 0.0V) 0.0 Altr.Ch.Power[dBc]@-40C -10.0 Altr.Ch.Power[dBc]@+25C Altr.Ch.Power[dBc]@+85C -20.0 Alternate Channel Power (dBc) -30.0 -40.0 -50.0 -60.0 -70.0 -80.0 -90.0 0.0 0.1 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 1.0 1.1 1.2 1.3 1.4 1.5 1.6 1.7 1.8 1.9 2.0  $V_{GC}\left(V\right)$ 





 $V_{GC}(V)$ 



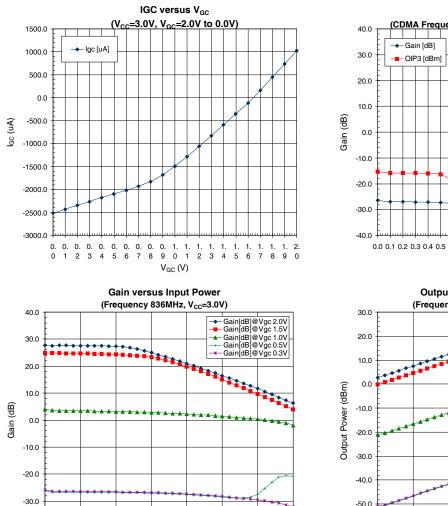
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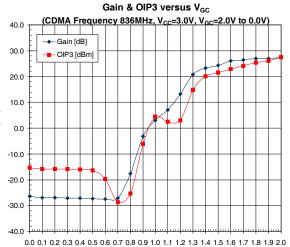
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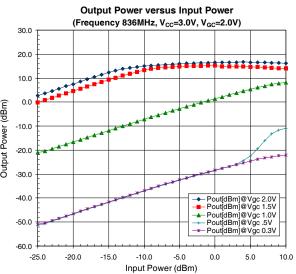


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-40.0

-25.0

-20.0

-15.0

-10.0

Input Power (dBm)

-5.0

0.0

5.0

10.0



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